EN: This Datasheet/Document is presented by the manufacturer.

Please visit our website for pricing and availability at www.hestore.hu.

KP-3216F3C

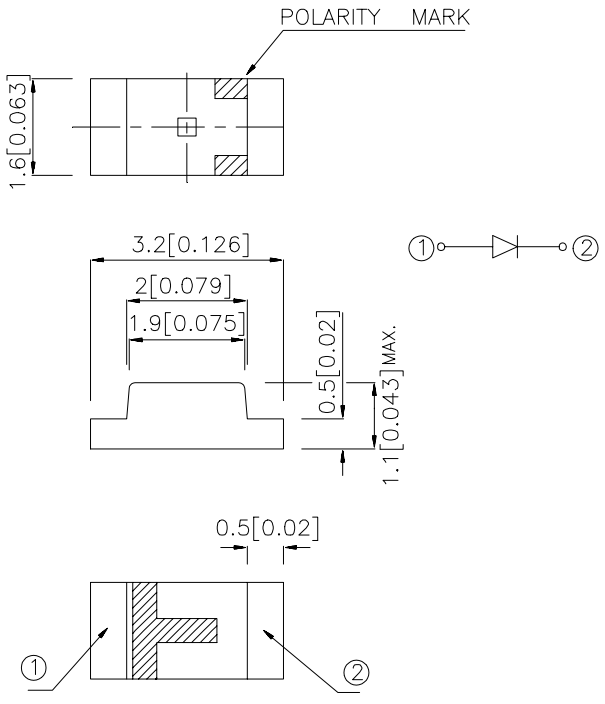
Features

- 3.2mmx1.6mm SMT LED, 1.1mm THICKNESS.
- LOW POWER CONSUMPTION.
- WIDE VIEWING ANGLE.
- IDEAL FOR BACKLIGHT AND INDICATOR.
- VARIOUS COLORS AND LENS TYPES AVAILABLE.
- PACKAGE : 2000PCS / REEL.

Description

F3 Made with Gallium Arsenide Infrared Emitting diodes.

Package Dimensions



Notes:
1. All dimensions are in millimeters (inches).
2. Tolerance is ±0.2(0.0079") unless otherwise noted.
3. Specifications are subject to change without notice.

Selection Guide

Part No.	Dice	Lens Type	Po (mW/sr) @ 20 mA		Viewing Angle
			Min.	Typ.	2θ1/2
KP-3216F3C	GaAs	WATER CLEAR	0.4	1.2	120°

Note:
1. θ1/2 is the angle from optical centerline where the luminous intensity is 1/2 the optical centerline value.

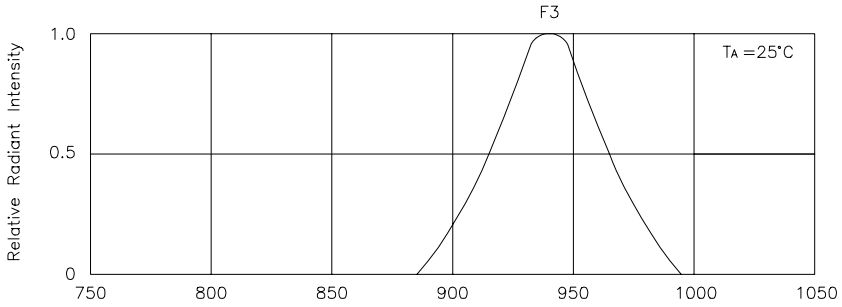
Electrical / Optical Characteristics at T_A=25°C

Parameter	P/N	Symbol	Typ.	Max.	Unit	Condition
Forward Voltage	F3	V_F	1.2	1.6	V	I_F=20mA
Reverse Current	F3	I_R	-	10	uA	V_R=5V
Capacitance	F3	C	90	-	pF	V_F=0V;f=1MHz
Peak Spectral Wavelength	F3	λP	940	-	nm	I_F=20mA
Spectral Bandwidth	F3	Δλ1/2	50	-	nm	I_F=20mA

Absolute Maximum Ratings at T_A=25°C

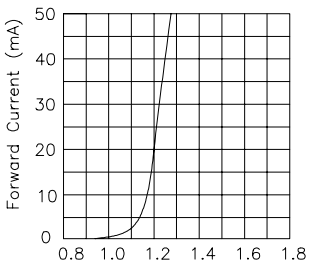
Parameter	Symbol	F3	Units
Power Dissipation	P_T	100	mW
Forward Current	I_F	50	mA
Peak Forward Current[1]	i_{FS}	1.2	A
Reverse Voltage	V_R	5	V
Operating Temperature	T_A	-40~ +85	°C
Storage Temperature	T_{STG}	-40~ +85	°C

Note:
1. 1/100 Duty Cycle, 10us Pulse Width.

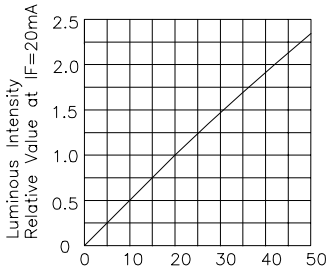


RELATIVE INTENSITY Vs. WAVELENGTH

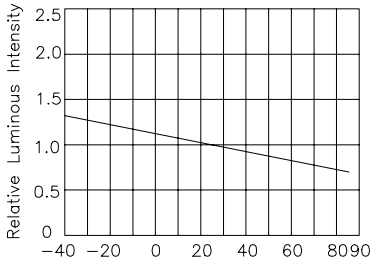
KP-3216F3C



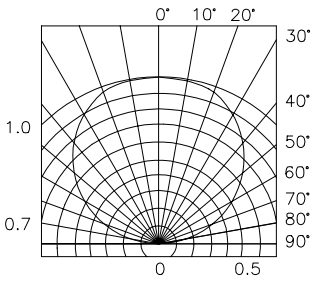
FORWARD CURRENT Vs.
FORWARD VOLTAGE



LUMINOUS INTENSITY Vs.
FORWARD CURRENT



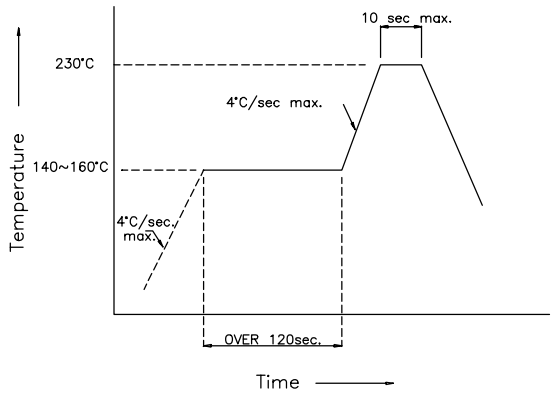
LUMINOUS INTENSITY Vs.
AMBIENT TEMPERATURE



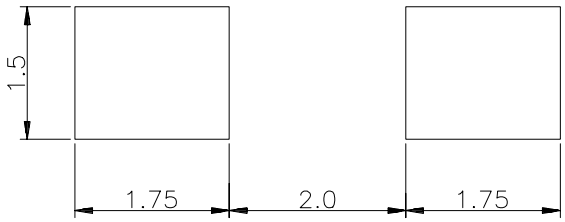
SPATIAL DISTRIBUTION

KP-3216F3C
SMT Reflow Soldering Instructions

Number of reflow process shall be less than 2 times and cooling process to normal temperature is required between first and second soldering process.



Recommended Soldering Pattern
(Units : mm)



Tape Specifications
(Units : mm)

